

Response Under 37 CFR § 1.116 Expedited Procedure

AF

501.42841X00

Jan. 18, 2006

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

KUMAGAI, et al.

Serial No.:

10/625,616

Filed:

July 24, 2003

For:

SEMICONDUCTOR DEVICE INCLUDING N-CHANNELED FETs AND P-CHANNELED FETs WITH IMPROVED DRAIN

CURRENT CHARACTERISTICS (As Amended)

Group:

2811

Exr. H. Vu

AMENDMENT AFTER FINAL

MS: AFTER FINAL

Commissioner of Patents

POB 1450

Alexandria, VA 22313-1450

Sir:

In response to the Final Office Action dated October 18, 2005, please amend the above-identified application as listed below and as set forth on the following pages:

Amendments to the Claims; and

Remarks are included following the amendments.

ìΚ

lu_